

# Intense UV and visible up-conversion luminescence from SiO<sub>2</sub>-BaGdF<sub>5</sub> glass-ceramics doped with Yb<sup>3+</sup>/Er<sup>3+</sup>, Yb<sup>3+</sup>/Tm<sup>3+</sup> or Yb<sup>3+</sup>/Er<sup>3+</sup>/Tm<sup>3+</sup>

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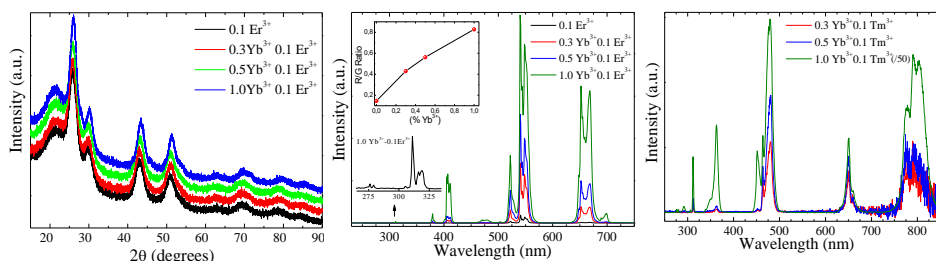
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UV-visible up-conversion luminescence of materials doped with rare-earths (RE<sup>3+</sup>) ions has attracted great interest due to their applications in areas such as temperature sensors, solid state lighting, solar cells, biomedical image and so on [1,2]. Herein we study the up-conversion properties of BaGdF<sub>5</sub> nanocrystals doped with Yb<sup>3+</sup>/Er<sup>3+</sup> and Yb<sup>3+</sup>/Tm<sup>3+</sup> pairs of ions. The sol-gel method, allowed us to obtain the precursor glasses that by adequate thermal treatments given rise to the glass-ceramics containing single-phase and homogeneous RE<sup>3+</sup>-doped BaGdF<sub>5</sub> nanocrystals. X-ray diffraction measurements confirmed the precipitation of cubic phase BaGdF<sub>5</sub> nanocrystal with cell parameter that varies as function of dopant concentration. Up-conversion luminescence reveals an efficient absorption around 980 nm, leading to intense UV and visible emissions, confirming an energy transfer up-conversion (ETU) mechanism responsible for the observed luminescence as well as the “saturation effect”. Additionally, color tuneability was quantified, in Yb-Er-Tm triply doped glass-ceramics, in terms of CIE diagram, and in particular a white colour, close to the standard equal energy white light illumination point, has been achieved for a certain thermal treatment.

## References

- [1] T. Grzyb, A. Tyminski, Journal of Alloys and Compounds, 660 (2016) 235-243.
- [2] A. Pandey, V. Kumar Rai, Applied Physics B Laser and Optics, 109, 4(2012) 611-616.
- [3] G. Wang, W. Qin, L. Wang, G. Wei, P. Zhu, R. Kim, Optics Express, 16, 16 (2008) 11907-11914.

## Figures



**Figure:** (a) XRD patterns of xYb<sup>3+</sup>-Er<sup>3+</sup>-doped SiO<sub>2</sub>-BaGdF<sub>5</sub> nGCs, where x=0, 0.3, 0.5 and 1.0, heat-treated at 650 °C. (b) Up-conversion emission spectra in xYb<sup>3+</sup>-Er<sup>3+</sup>-doped SiO<sub>2</sub>-BaGdF<sub>5</sub> nGCs (mol %) heat-treated at 650 °C, under 980 nm excitation at 300 mW pump power. (c) Up-conversion emission spectra in xYb<sup>3+</sup>-Tm<sup>3+</sup>-doped SiO<sub>2</sub>-BaGdF<sub>5</sub> nGCs (mol %) heat-treated at 650 °C, under 980 nm excitation at 300 mW pump power.